

TO-92 Plastic-Encapsulate Transistors

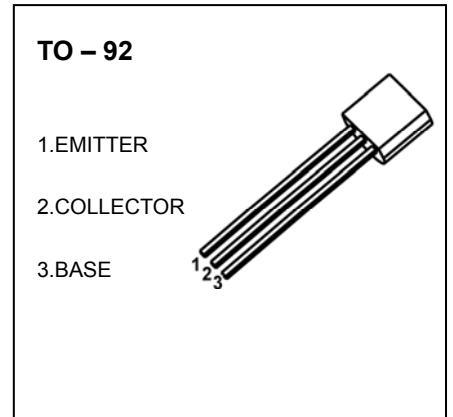
STBV32/B TRANSISTER (NPN)

FEATURES

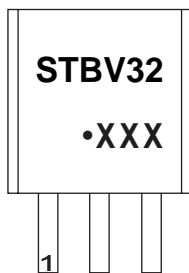
- Medium Voltage Capability
- Low Spread of Dynamic Parameters
- Minimum Lot-to-lot Spread for Reliable Operation
- Very High Switching Speed

APPLICATIONS

- Electronic Ballasts for Fluorescent Lighting

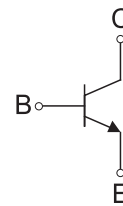


MARKING



STBV32=Device code
Solid dot = Green molding compound device,
if none, the normal device
XXX=Code

Equivalent Circuit



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
STBV32/B	TO-92	Bulk	1000pcs/Bag
STBV32/B-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	700	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	9	V
I _C	Collector Current	1	A
P _C	Collector Power Dissipation	1.1	W
R _{θJA}	Thermal Resistance From Junction To Ambient	114	°C/W
T _J	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS

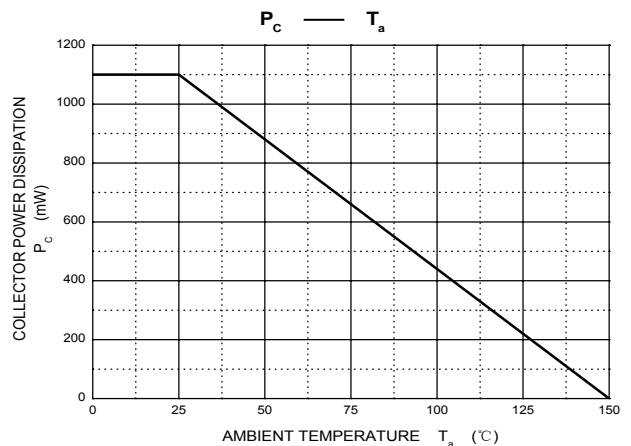
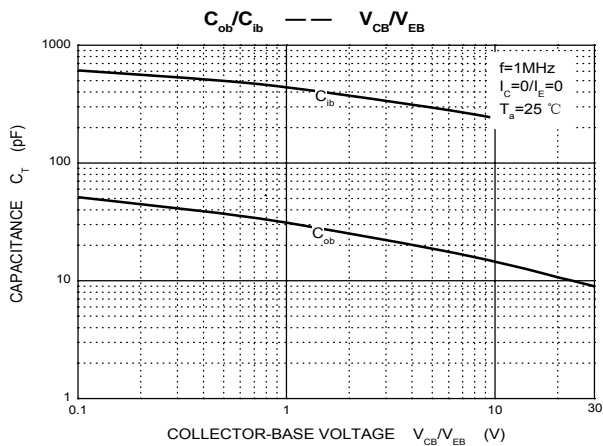
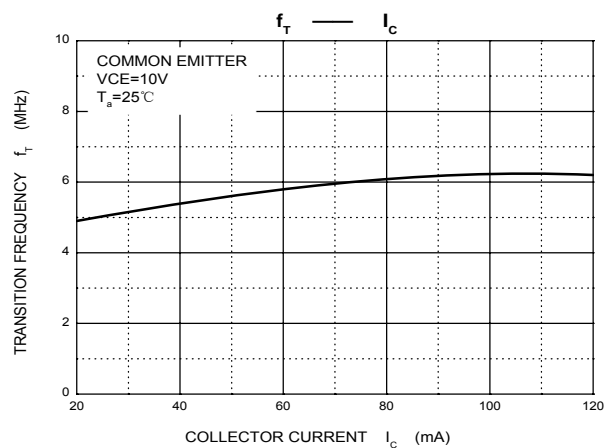
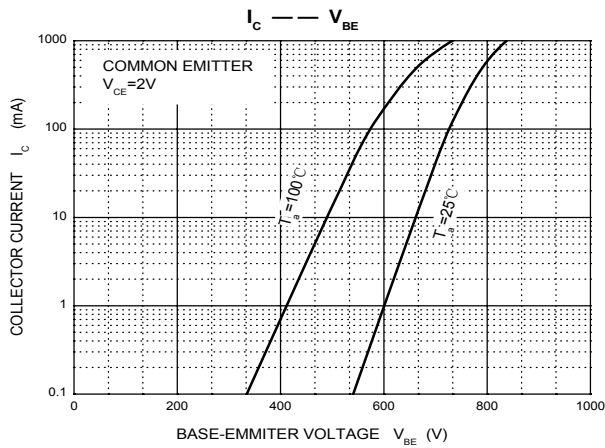
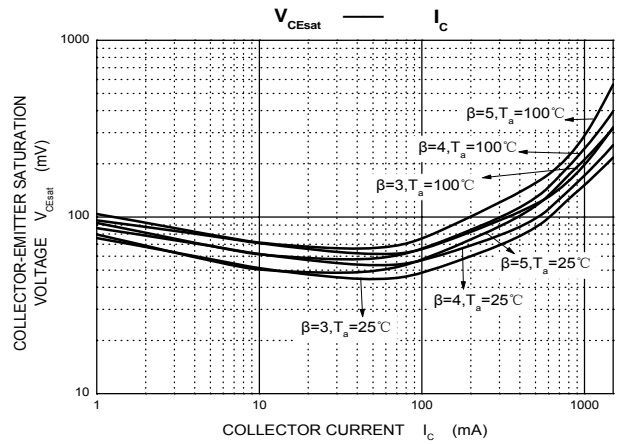
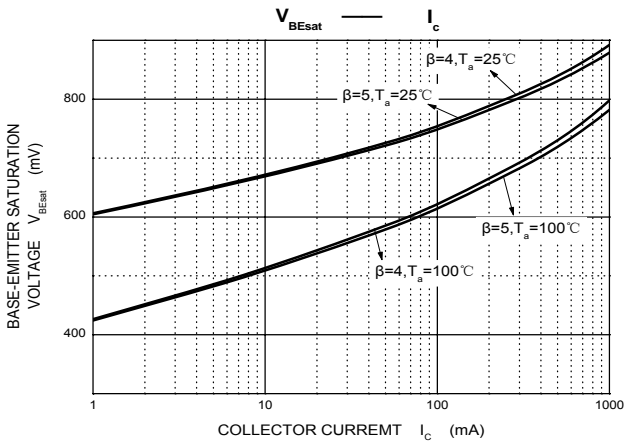
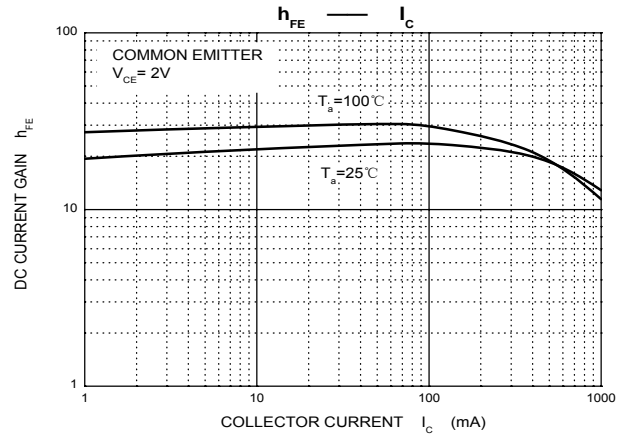
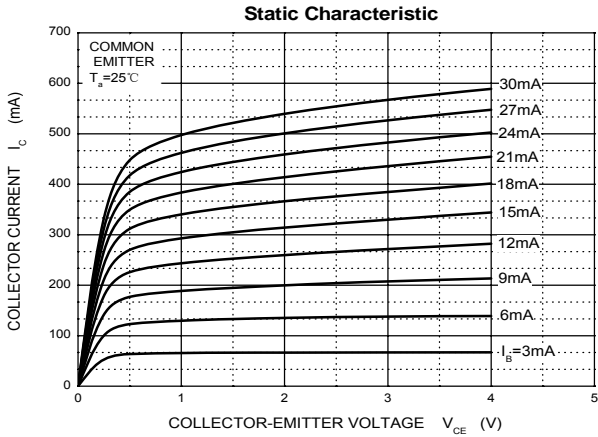
$T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}^*$	$I_C=1\text{mA}, I_E=0$	700			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}^*$	$I_C=10\text{mA}, I_B=0$	400			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=10\text{mA}, I_C=0$	9			V
Collector cut-off current	I_{CEO}	$V_{BE}=-1.5\text{V}, V_{CE}=700\text{V}$			1	mA
Emitter cut-off current	I_{EBO}	$V_{EB}=7\text{V}, I_C=0$			100	μA
DC current gain	$h_{FE(1)}^*$	$V_{CE}=2\text{V}, I_C=0.5\text{A}$	8		35	
	$h_{FE(2)}^*$	$V_{CE}=2\text{V}, I_C=1\text{A}$	5		25	
Collector-emitter saturation voltage	$V_{CE(sat)(1)}^*$	$I_C=0.5\text{A}, I_B=0.1\text{A}$			0.5	V
	$V_{CE(sat)(2)}^*$	$I_C=1\text{A}, I_B=0.25\text{A}$			1	V
	$V_{CE(sat)(3)}^*$	$I_C=1.5\text{A}, I_B=0.5\text{A}$			1.5	V
Base-emitter saturation voltage	$V_{BE(sat)(1)}^*$	$I_C=0.5\text{A}, I_B=0.1\text{A}$			1	V
	$V_{BE(sat)(2)}^*$	$I_C=1\text{A}, I_B=0.25\text{A}$			1.2	V

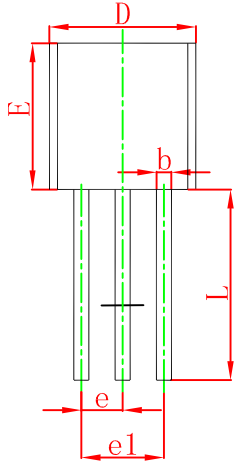
*Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 1.5\%$.

Typical Characteristics

STBV32/B

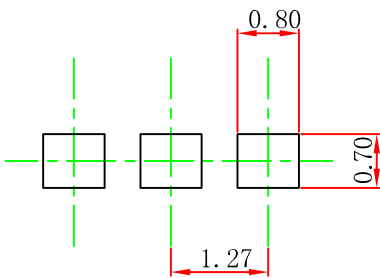


TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

TO-92 Suggested Pad Layout



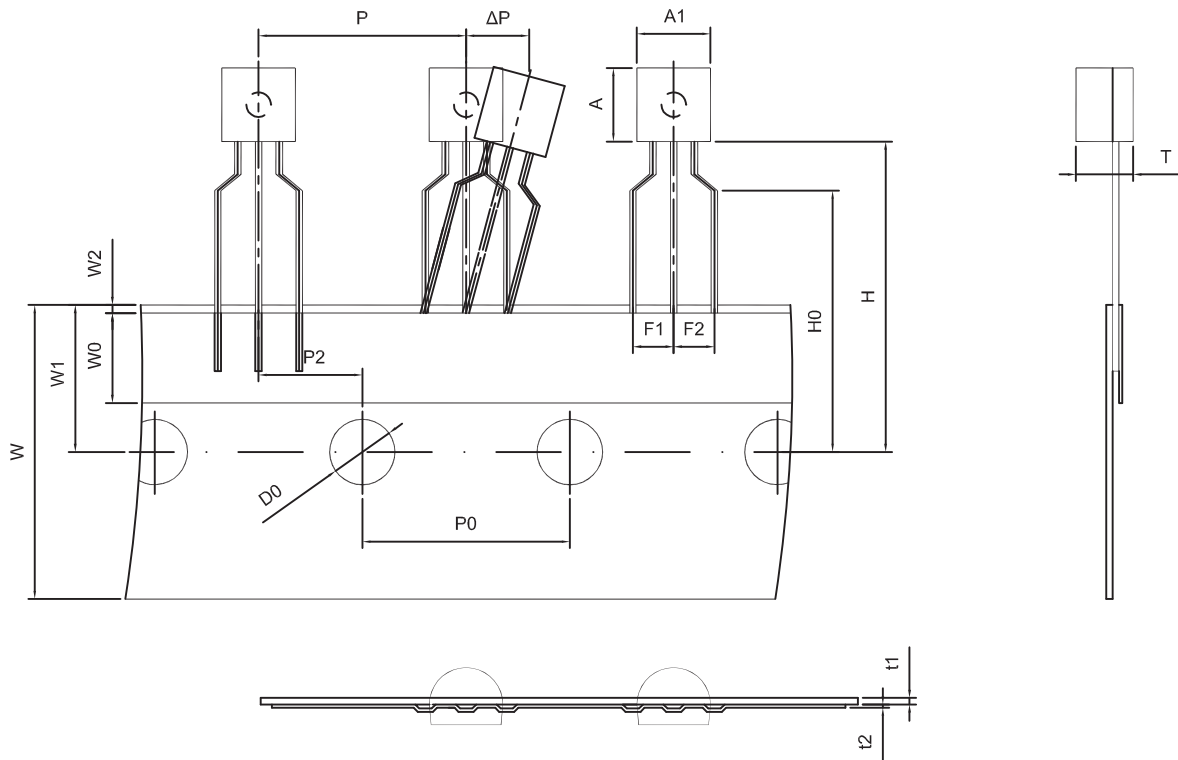
Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

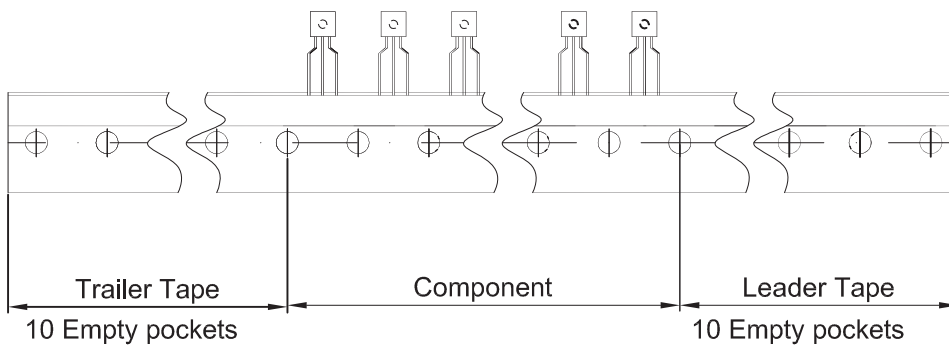
NOTICE

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TO-92 PACKAGE TAPEING DIMENSION



Dimiensions are in millimeter								
A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250